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CO hydrogenation over a rhodium vanadate catalyst: Reduction and regeneration of RhVO₄ on SiO₂

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Abstract

The hydrogenation of CO over an Rh vanadate (RhVO₄) catalyst supported on SiO₂ (RhVO₄/SiO₂) has been investigated after H₂ reduction at 500°C, and the results are compared with those of vanadia-promoted (V₂O₅–Rh/SiO₂) and unpromoted Rh/SiO₂ catalysts. The mean size of Rh particles, which were dispersed by the decomposition of RhVO₄ after the H₂ reduction, was smaller (41 Å) than those (91–101 Å) of V₂O₅–Rh/SiO₂ and Rh/SiO₂ catalysts. The RhVO₄/SiO₂ catalyst showed higher activity and selectivity to C₂ oxygenates than the unpromoted Rh/SiO₂ catalyst after the H₂ pretreatment. The CO conversion of the RhVO₄/SiO₂ catalyst was much higher than that of V₂O₅–Rh/SiO₂ catalyst, and the yield of C₂ oxygenates increased. We also found that the RhVO₄/SiO₂ catalyst can be regenerated by calcination or O₂ treatment at high temperature after the reaction. © 1998 Elsevier Science B.V. All rights reserved.

Keywords: CO hydrogenation; RhVO₄; SMSI; SMOI; Regeneration; Redispersion; C₂ oxygenates

1. Introduction

Vanadia-promoted Rh catalysts have been reported to have a high activity and selectivity of the syngas (CO+H₂) conversion for the production of C₂ oxygenates such as ethanol, acetic acid [1,2]. In both vanadia-supported and vanadia-promoted systems, it is suggested that the Rh particles are partially covered by vanadium oxide after a high-temperature reduction (so called, SMSI: strong metal-support interaction) [3–5] and that the role of the vanadium oxide promoter is to enhance the CO dissociation and/or the insertion of CO into metal-carbon bond [1,2]. We have found that a ternary compound containing rhodium, a transition metal and oxygen such as RhNbO₄, RhVO₄ and

MnRh₂O₄ can be formed on an SiO₂ support by mutual interaction between Rh and oxides (vanadia, etc.) during calcination treatment in O_2 or in air at high temperature (700–900°C) [3–6]. For instance, RhVO₄ is decomposed to highly dispersed Rh metal and reduced vanadium oxide (VO_x) by H₂ reduction above 300°C, and a strong metal-oxide (Rh-VO_x) interaction (SMOI) is induced on SiO₂ [6-8]. One of the interesting characteristic features in this system is that regeneration of RhVO₄ is possible by the calcination treatment (see Fig. 1). Therefore, redispersion of Rh metal can be achieved by the calcination and reduction treatments of a spent (coked and/or sintered) Rh catalyst. The aim of this work was to investigate the catalytic performance of the RhVO₄/SiO₂ system for the syngas conversion and to compare the results with those of vanadia-promoted (V₂O₅-Rh/SiO₂) and unpromoted Rh/SiO₂ catalysts.

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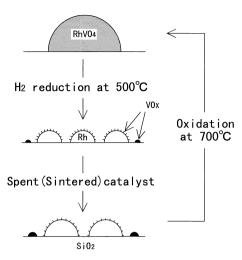


Fig. 1. A model for redispersion of Rh and regeneration of RhVO₄ on SiO₂ support.

2. Experimental

The SiO_2 support (JRC-SIO-7) was provided as Japan Reference Catalyst (JRC) [9]. The SiO_2 support, which had been precalcined in air at 900° C (BET surface area, $81 \text{ m}^2/\text{g}$), was first impregnated with an aqueous solution of RhCl₃ (4 wt% Rh), then dried in air at 120° C overnight. V_2O_5 –Rh/SiO₂ and RhVO₄/SiO₂ catalysts were prepared by impregnating this sample with an aqueous solution of NH₄VO₃ (atomic ratio of V/Rh was 1 and 2, respectively), followed by calcination in air at 800° C for 3h. For a comparison, unpromoted Rh/SiO₂ catalyst was also prepared by air calcination at 800° C.

CO hydrogenation over the Rh catalysts after H₂ reduction at 500°C was carried out in a flow reactor system using mass flow controller (Nippon Tylan, Aera FC-260E) at atmospheric pressure using a 1:3 mixture of CO and H₂ (3 cm³/g_{cat} min). For the measurement we used one sample of catalyst for increasing temperature and the steady-state reactions were established after 1 h at each temperature. Analysis of the products was performed by on-line gas chromatograph system equipped with TCD detector (Shimadzu GC-8A, Chromatopac C-R3A) using Porapak Q column (i.d. 3 mm, length 2 m) in He carrier gas (25 cm³/min). The selectivity of products is expressed as carbon efficiency (%), and the yield (CO conversion×selectivity) of C₂ oxygenates is calculated from

the total amount of C₂H₅OH, CH₃COOH, CH₃CHO and HOCH₂CH₂OH.

X-ray diffraction (XRD) measurements were carried out by an X-ray diffractometer (Rigaku) equipped with a graphite monochromator for Cu K_{α} (40 kV, 30 mA) radiation. The mean Rh particle size was calculated from the XRD line broadening measurement using the Scherrer equation [4–6].

3. Results and discussion

Fig. 2 shows XRD patterns of vanadia-promoted Rh/SiO₂ catalysts (V/Rh=1 and 2) after the calcination at 800°C. In the case of V/Rh=2, the peaks of RhVO₄ appeared after the calcination at 800°C. But in the case of V/Rh=1, only trace of a peak of RhVO₄ appeared and the other peaks were assigned to Rh₂O₃. These results of the XRD measurements indicate that RhVO₄ was formed on SiO₂ (SIO-7) by the calcination with an excess amount of V. Beutel et al. [13] also recently investigated the formation of RhVO₄ with the atomic ratio of V/Rh=4 on an SiO₂ surface. On the other hand, our previous study [6] using a different SiO₂ support (JRC-SIO-3; BET surface area, 40 m²/g) showed that, even with the atomic ratio of V/Rh=1, RhVO₄ was formed almost exclusively after the calcination at 700°C. These different behaviors may be due to different natures (BET surface area, etc.) of

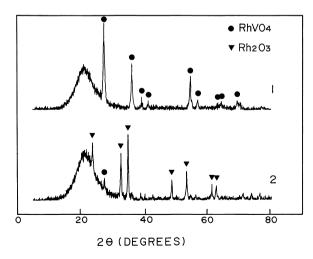


Fig. 2. X-ray diffraction patterns of RhVO₄/SiO₂ and V₂O₅–Rh/SiO₂ catalysts after calcination in air at 800° C: (1) V/Rh=2, and (2) V/Rh=1.

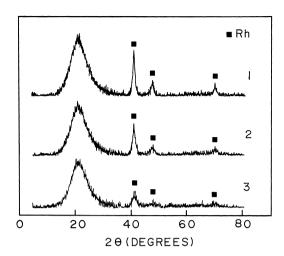


Fig. 3. X-ray diffraction patterns of RhVO₄/SiO₂, V_2O_5 -Rh/SiO₂ and Rh/SiO₂ catalysts after H₂ reduction at 500°C: (1) Rh/SiO₂, (2) V_2O_5 -Rh/SiO₂, and (3) RhVO₄/SiO₂.

SiO₂. In fact, we have already reported different behaviors of Rh-Nb₂O₅ interaction supported on different SiO₂ supports [14]. The stronger the vanadia– SiO₂ interaction is, the more excess amount of V₂O₅ may be needed for the formation of RhVO₄. In practice, vanadia may be highly dispersed and/or present as isolated VO_x species in the vanadia-promoted Rh/ SiO₂ catalysts (V/Rh=1 and 2), because no peak of V₂O₅ was observed in Fig. 2. Inumaru et al. [10–12] have recently reported that V-oxide is present as isolated VO_x species on SiO₂ in low V₂O₅ loading (<5 wt%), and in high V_2O_5 loading (>5 wt%) Voxide is present as V₂O₅ particles. In this paper the catalyst with V/Rh=2 was designated as RhVO₄/SiO₂, and the catalyst with V/Rh=1 was designated as V₂O₅-Rh/SiO₂.

Fig. 3 shows XRD patterns of RhVO₄/SiO₂, V₂O₅–Rh/SiO₂ and unpromoted Rh/SiO₂ catalysts, which were calcined in air at 800°C, and then reduced in H₂ at 500°C. The peaks assigned to Rh were observed in each pattern and no peak of V-oxide was observed. Broadening of the widths of the Rh peaks was observed for the RhVO₄/SiO₂. Since no peak of V-oxide was observed, vanadia on SiO₂ was highly dispersed, which is in good agreement with the previous results [6,7]. As shown in Table 1, Rh was more highly dispersed (41 Å) after the decomposition of RhVO₄ (202 Å) by H₂ reduction at 500°C than those

Table 1
Particle size and catalytic activity and selectivity of vanadiapromoted and unpromoted Rh/SiO₂ catalysts

| Catalyst | RhVO ₄ / SiO ₂ | V ₂ O ₅ –Rh/ SiO ₂ | Rh/ SiO ₂ |
|--|---|--|-----------------------------------|
| | | | |
| Compound ^a | 202 | 268 | 229 |
| | $(RhVO_4)$ | (Rh ₂ O ₃) | (Rh ₂ O ₃) |
| Rh ^b | 41 | 91 | 101 |
| CO conversion (%) ^c | 69.7 | 10.6 | 3.8 |
| Selectivity (%) ^c | | | |
| CO_2 | 22.9 | 10.8 | 8.1 |
| CH_4 | 38.3 | 9.3 | 42.1 |
| C_{2+}^{d} | 15.4 | 19.8 | 38.7 |
| MeOH | 5.9 | 4.9 | 5.1 |
| C ₂ oxygenates ^e | 17.5 | 55.2 | 6.0 |
| Yield (%) ^c | | | |
| C ₂ oxygenates ^e | 12.2 | 5.9 | 0.2 |

^aAfter calcination in air at 800°C.

(91-101 Å) of V_2O_5 -Rh/SiO₂ and unpromoted Rh/SiO₂ catalysts.

Fig. 4 shows CO conversion using the RhVO₄/SiO₂, V₂O₅-Rh/SiO₂ and unpromoted Rh/SiO₂ catalysts after H₂ reduction as a function of reaction temperature. The activity of the RhVO₄/SiO₂ catalyst is much higher than that of the V₂O₅-Rh/SiO₂ catalyst. The order of the activity of CO hydrogenation is as fol-RhVO₄/SiO₂>V₂O₅-Rh/SiO₂>Rh/SiO₂. shown in Table 1, for the unpromoted Rh/SiO₂ catalyst CO conversion is 3.8% at 225°C. For the V₂O₅-Rh/SiO₂ catalyst CO conversion is 10.6%, and for RhVO₄/SiO₂ catalyst it is 69.7% at 225°C. The products are CO₂, CH₄, C₂₊ hydrocarbons, CH₃OH, and C₂ oxygenates (C₂H₅OH, CH₃COOH, CH₃CHO and HOCH₂CH₂OH). In the RhVO₄/SiO₂ catalyst a strong interaction between Rh and VO_x (SMOI) may be induced after the H₂ reduction, which may be different from that after the reduction of the V₂O₅-Rh/SiO₂. It should be noted that a metal-oxide (Rh-VO_x) interaction was also induced by the H₂ reduction of the V_2O_5 -Rh/SiO₂ at 500°C, because the activity and the selectivity to C₂ oxygenates were higher than those of the unpromoted Rh/SiO₂ catalyst (Table 1). Fig. 5

^bAfter H₂ reduction at 500°C.

^cReaction temperature is 225°C.

^dHydrocarbons containing two or more C atoms.

^eAmount of ethanol, acetic acid, acetaldehyde and ethylene glycol.

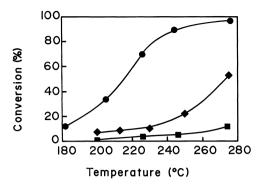


Fig. 4. The activity of CO hydrogenation on RhVO₄/SiO₂, V₂O₅–Rh/SiO₂ and Rh/SiO₂ catalysts after H₂ reduction at 500° C: (\bullet) RhVO₄/SiO₂, (\bullet) V₂O₅–Rh/SiO₂, and (\blacksquare) Rh/SiO₂.

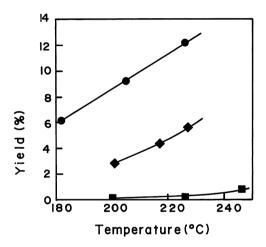


Fig. 5. The yield of C_2 oxygenates (amount of C_2H_5OH , CH_3COOH , CH_3CHO and $HOCH_2CH_2OH$) on $RhVO_4/SiO_2$, V_2O_5-Rh/SiO_2 and Rh/SiO_2 catalysts after H_2 reduction at $500^{\circ}C$: (\spadesuit) $RhVO_4/SiO_2$, (\spadesuit) V_2O_5-Rh/SiO_2 , and (\blacksquare) Rh/SiO_2 .

shows C_2 oxygenates yield as a function of reaction temperature. Using the unpromoted Rh/SiO₂ catalyst resulted in low yield of C_2 oxygenates, on the other hand using the RhVO₄/SiO₂ catalyst resulted in high yield of C_2 oxygenates. The selectivity to C_2 oxygenates decreased with increasing of CO conversion because of the secondary reactions to form CO_2 and CH_4 , but the yield of C_2 oxygenates increased. These results suggest that the SMOI induced by the decomposition of RhVO₄ in H_2 strongly enhances the CO dissociation step, which leads to the high activity. Lee et al. [2] have reported that Rh–VO_x interaction

enhances mainly CO insertion, which leads to the formation of C_2 oxygenates. On the other hand, Kip et al. [1] have reported that the main promoter action is CO dissociation. This investigation has revealed that the decomposition of the RhVO₄/SiO₂ catalyst enhances not only the selectivity to C_2 oxygenates (compared with the unpromoted Rh/SiO₂ catalyst), but also the CO conversion dramatically (compared with the V_2O_5 –Rh/SiO₂ catalyst).

It should be noted again that the Rh particle size after the decomposition of RhVO₄ was 41 Å (Table 1). Arakawa et al. [15] have reported that Rh/SiO₂ catalysts, in which the size of Rh was about 30-40 Å, were most active for the formation of C₂ oxygenates. Gronchi et al. [16] have also reported that CO insertion occurred on Rh/V₂O₃, where the size of Rh was 40 Å. Therefore, we consider that the metal dispersion (Rh ensembles) may play a part in the formation of C₂ oxygenates. However, the most important point is that there is a strong Rh-VO_x interaction in the RhVO₄/ SiO₂ catalyst system. In our RhVO₄/SiO₂ system, we agree with the idea [1,17] that the main promoter action of VO_x is CO dissociation. Although an Rh- VO_x interaction is also present in the V_2O_5 -Rh/SiO₂ catalyst, more intimate contact between Rh and VO_x (i.e. a strong metal-oxide interaction (SMOI)) resulted from the decomposition of the RhVO₄/SiO₂. The SMOI increased the activity of CO hydrogenation, and hence the yield of C2 oxygenates was increased.

In order to demonstrate the catalytic performance of the RhVO₄/SiO₂ system, an experiment of "regeneration of catalysts" was carried out, as shown in Fig. 6. In the initial run, CO hydrogenation was performed on a fresh RhVO₄/SiO₂ catalyst after H₂ reduction at 500°C. Then, the catalyst was intentionally treated in He gas at 700°C for 2 h. After the catalytic activity measurement, the catalyst was retreated in O2 at 700°C, followed by H₂ reduction at 500°C (regeneration of RhVO₄ and redispersion of Rh). For a comparison, a 4 wt% Rh/SiO₂ catalyst prepared by the calcination at 500°C was used (the O2 retreatment was also done at 500°C), because the activity of the Rh/SiO₂ prepared by the calcination at 800°C was too low to observe the change of the conversion by the He treatment. As shown in Fig. 6, the activity of the RhVO₄/SiO₂ catalyst was decreased severely after the He treatment, but increased to almost initial level by the calcination and reduction treatments. On the

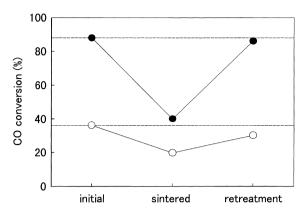


Fig. 6. The change in the activity of CO hydrogenation (245°C) on RhVO₄/SiO₂ (\bullet), and Rh/SiO₂ (\bigcirc) after the sequential treatments: initial (H₂ 500°C), sintered (He 700°C), and retreated (O₂ 700°C for RhVO₄/SiO₂ or O₂ 500°C for Rh/SiO₂, followed by H₂ reduction at 500°C).

other hand, the recovery of the activity after the He treatment followed by O_2 and H_2 treatments at 500° C was not complete for the Rh/SiO₂ catalyst.

Acknowledgements

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